

O-band 56Gbaud InP Mach-Zehnder-Modulator

General Description

The Indium-Phosphide Mach-Zehnder-Modulator is ideally suited for optical transport applications within the O-band. It features a unique traveling-wave-electrode design, resulting in high bandwidth and zero chirp.



Applications

56Gbaud, 4PAM, 2PSK

Features

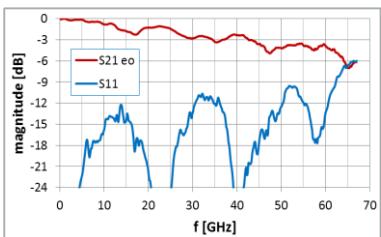
- O-band operations (1280-1340nm)
- High bandwidth
- Traveling-wave-electrode design with zero chirp
- Evaluation-board with integrated TEC-control included
- Adjustable $V\pi$

Operating Conditions / Absolute Maximum Ratings

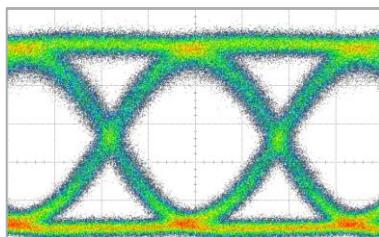
Parameter	Unit	Min	Typ	Max
Optical wavelength	nm	1280	1310	1340
Optical input power	dBm		10	16
Temperature	°C		25	50
Bias voltage V_{bias}	V	3		10
Phase-voltage	V	-10		0
TEC-control supply voltage	V		5	
TEC-control driving current	A		0.3	1

Performance

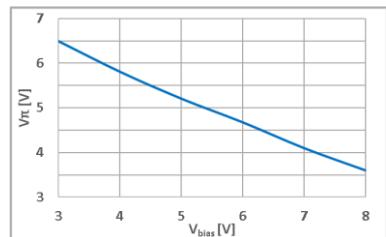
Parameter	Symbol	Unit	Typ	Comments
Insertion loss	IL	dB	8.5	@ max. transmission
Extinction ratio (dynamic)	ER	dB	>10	@ 56Gbaud
Extinction ratio (DC)	ER	dB	>20	
3dB EO cut-off frequency	f_{3dB}	GHz	35	
Bias voltage	V_{bias}	V	8	
Phase voltage	P1 P2	V	-3	quadrature point
$V\pi$		V	3.5	@ $V_{bias} = +8V$



Small signal response



Eye diagram @ 56Gbaud (RF-V_{pp}: 3.5V)



$V\pi = f(V_{bias}) @ 1310 \text{ nm}$

HHI reserves the right to change specifications without any prior notice at any time

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General Instructions / Precautions

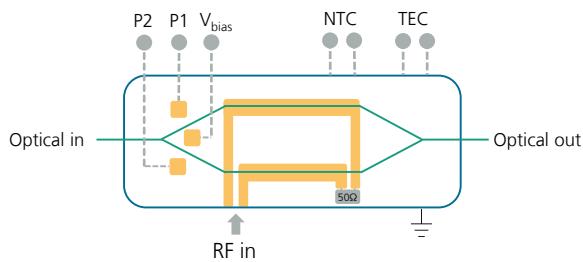
An InP-Mach-Zehnder-Modulator contains several semiconductor-p-i-n junctions, a faulty DC-operation will result in an irreversible damage of the device. Please use the electric circuit diagram for correct DC-wiring. Don't exceed maximum values for Phase- and Bias-voltages. V_{bias} has to be always positive, referenced against GND. Phase voltages has to be always negative, referenced against V_{bias} . Use voltage sources with integrated current limiter.

Limits: V_{bias} : 3 mA, Phase: 1 mA.

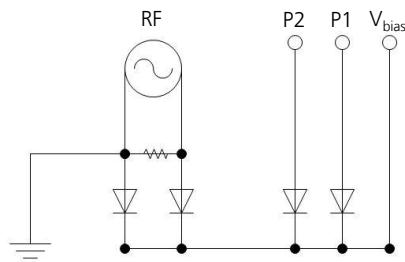
Connections / Specifications

- Optical connections: SSMF with FC/APC connectors
- RF: single ended, 1.85mm female
- DC: Evaluation board with integrated TEC-control and preconfigured cable assembly (4mm banana jacks)

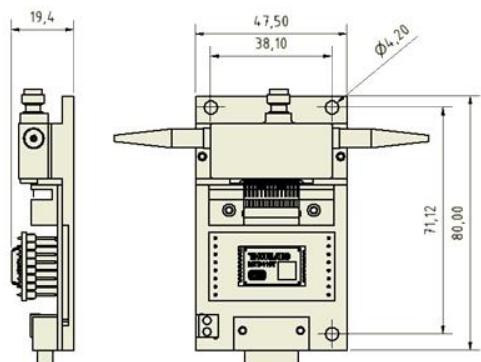
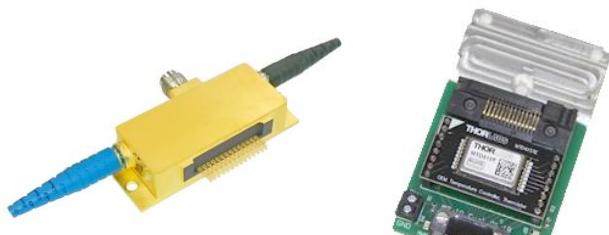
Device diagram



Electric circuit diagram



Drawings / pictures evaluation board and module



Part Numbers

- Module: MZM_M_O_35_22
- Evaluation board: EVAL_M_22

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